



45V PNP SMALL SIGNAL TRANSISTOR IN SOT523

Features

- BV_{CEO} > -45V
- I_C = -100mA Collector Current
- Epitaxial Planar Die Construction
- Ultra-Small Surface Mount Package
- Complementary NPN Type: BC847AT, BT, CT
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

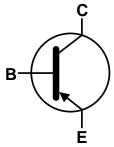
Mechanical Data

- Case: SOT523
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads.
 Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.002 grams (Approximate)

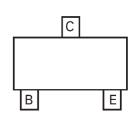








Device Symbol



Pin-Out Top View

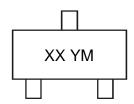
Ordering Information (Note 4)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
BC857AT-7-F	AEC-Q101	3V	7	8	3,000
BC857BT-7-F	AEC-Q101	3W	7	8	3,000
BC857CT-7-F	AEC-Q101	3G	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information



 $\begin{array}{l} XX = Product\ Type\ Marking\ Code \\ YM = Date\ Code\ Marking \\ Y\ or\ \overline{Y} = Year\ (ex:\ F=2018) \\ M\ or\ \overline{M} = Month\ (ex:\ 9=September) \end{array}$

Date Code Key

Bate Code	1103												
Year	201	8	2019	2020	2021	2022	2023	202	4 20	25 2	2026	2027	2028
Code	F		G	Н	I	7	K	L	N	Λ	N	0	Р
Mont	h	Jar	Fel	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	9	1	2	3	4	5	6	7	8	9	0	N	D



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-50	V
Collector-Emitter Voltage	V_{CEO}	-45	V
Emitter-Base Voltage	V_{EBO}	-6	V
Collector Current	Ic	-100	mA

Thermal Characteristics ($@T_A = +25^{\circ}C$, unless otherwise specified.)

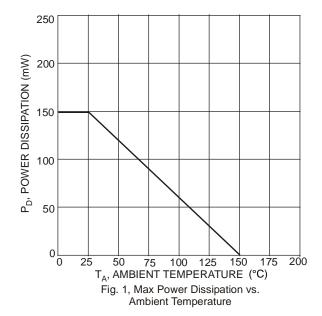
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P _D	150	mW
Thermal Resistance, Junction to Ambient (Note 5)	R _{0JA}	833	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

ESD Ratings (Note 6)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge – Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge – Machine Model	ESD MM	400	V	С

Notes:

Thermal Characteristics and Derating Information



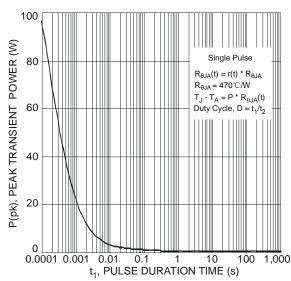
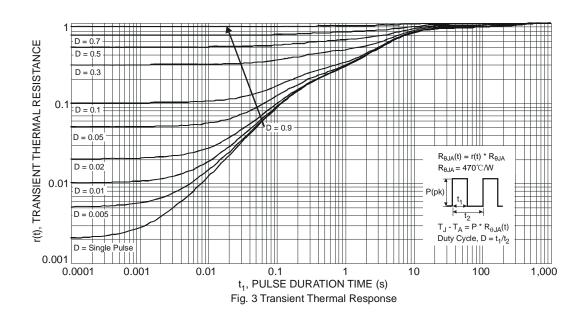


Fig. 2 Single Pulse Maximum Power Dissipation

^{5.} For a device mounted with the collector lead on minimum recommended pad layout 1oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state. 6. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information (Cont.)



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition		
OFF CHARACTERISTICS (Note 7)	OFF CHARACTERISTICS (Note 7)							
Collector-Base Breakdown Voltage	BV _{CBO}	-50		_	V	$I_C = -100\mu A, I_E = 0$		
Collector-Emitter Breakdown Voltage		BV _{CEO}	-45		_	V	$I_C = -1 \text{mA}, I_B = 0$	
Emitter-Base Breakdown Voltage		BV _{EBO}	-6		_	V	$I_E = -100\mu A, I_C = 0$	
ON CHARACTERISTICS (Note 7)							·	
DC Current Gain	Current Gain A B C	h _{FE}	125 220 420	— 290 520	250 475 800		V _{CE} = -5V, I _C = -2mA	
Collector-Emitter Saturation Voltage		V _{CE(SAT)}	_	_	-300 -650	mV	$I_C = -10\text{mA}, I_B = -0.5\text{mA}$ $I_C = -100\text{mA}, I_B = -5\text{mA}$	
Base-Emitter Saturation Voltage		V _{BE(SAT)}	_	-700 -900	_	mV	$I_C = -10mA$, $I_B = -0.5mA$ $I_C = -100mA$, $I_B = -5mA$	
Base-Emitter Voltage		V _{BE(ON)}	-600 —	_	-750 -820	mV	$V_{CE} = -5V, I_{C} = -2mA$ $V_{CE} = -5V, I_{C} = -10mA$	
Collector-Emitter Cutoff Current		I _{CBO}	<u> </u>	_	-15 -4	nΑ μΑ	$V_{CB} = -30V$ $V_{CB} = -30V$, $T_A = +150$ °C	
SMALL SIGNAL CHARACTERISTIC	S							
Output Capacitance	Сово		_	4.5	pF	$V_{CB} = -10V$, $f = 1MHz$		
Current Gain-Bandwidth Product		f _T	100	_	_	MHz	$V_{CE} = -5V, I_{C} = -10mA,$ f = 100MHz	
Noise Figure	NF		_	10	dB	I_C = -0.2mA, V_{CE} = -5V, R_S = 2k Ω , f = 1MHz, BW = 200Hz		

Note: 7. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

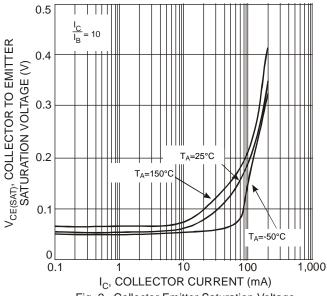


Fig. 2, Collector Emitter Saturation Voltage vs. Collector Current

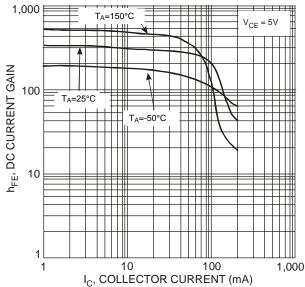


Fig. 3, DC Current Gain vs. Collector Current

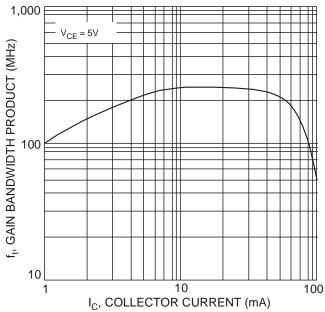


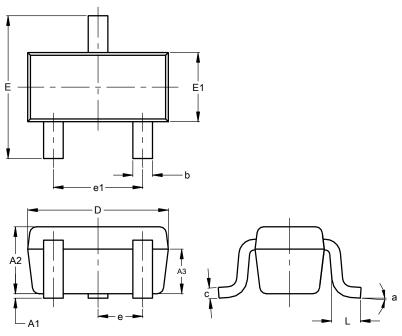
Fig. 4, Gain Bandwidth Product vs. Collector Current



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT523

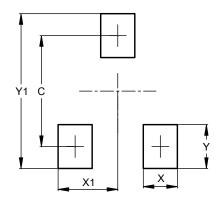


	SOT523						
Dim	Min	Max	Тур				
Α	0.60	0.80	0.75				
A1	0.00	0.10	0.05				
A3	0.45	0.65	0.50				
b	0.15	0.30	0.22				
С	0.10	0.20	0.12				
D	1.50	1.70	1.60				
Е	1.45	1.75	1.60				
E1	0.75	0.85	0.80				
е		0.50 BS	C				
e1	0.90	1.10	1.00				
L	0.20	0.40	0.33				
а	0°		8°				
Al	All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT523



Dimensions	Value
С	1.29
Х	0.40
X1	0.70
Y	0.51
Y1	1.80



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